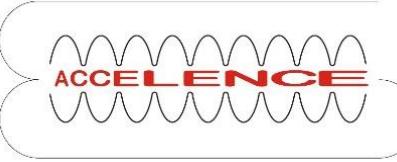




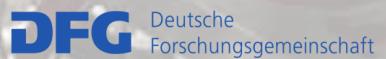
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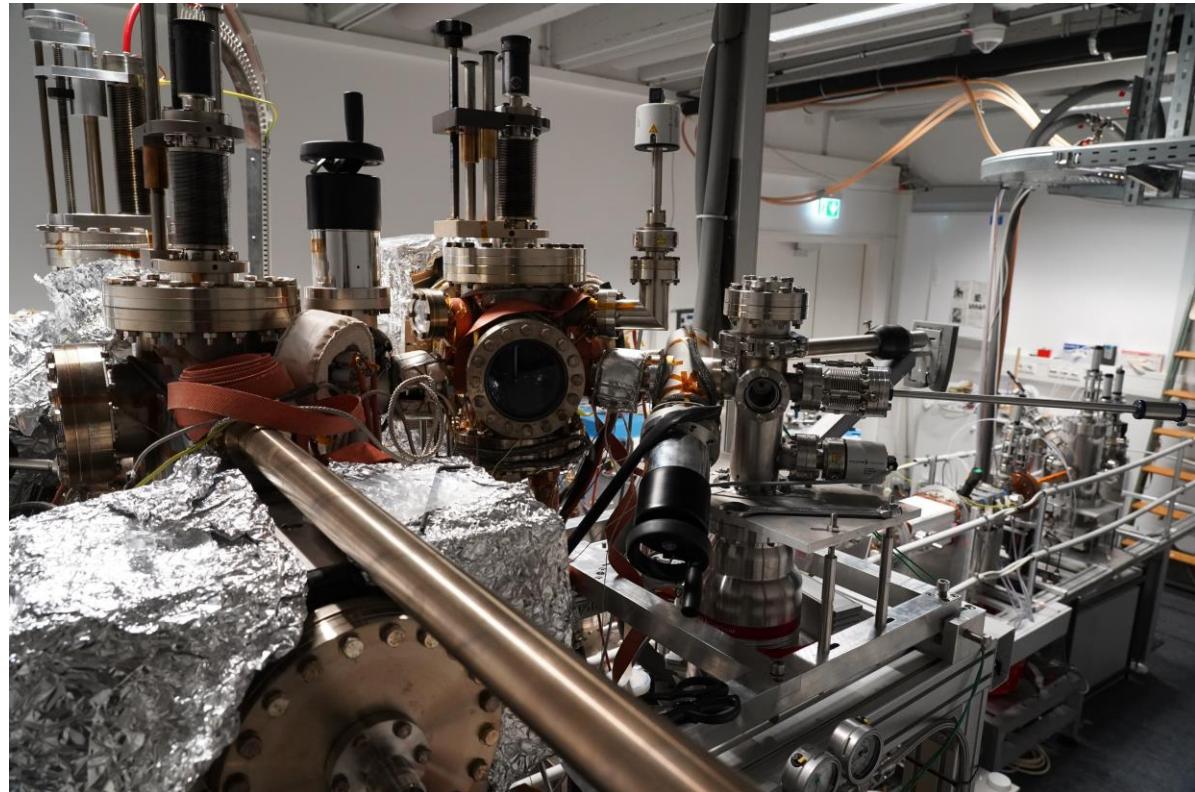
# Activation studies for GaAs photocathodes at Photo-CATCH\*

M. Herbert – J. Enders, M. Engart, M. Meier, J. Schulze, V. Wende, V. Winter

\*Supported by BMBF (05H18RDRB1) and by DFG (GRK 2128 „AccelencE“, project-id 264883531)



## GaAs photocathode research at Photo-CATCH



- Laser-induced photo-emission
- High degree of spin-polarization possible
- XHV required ( $\sim 10^{-11}$  mbar)
- used in DC HV guns
- low- to medium-intensity electron beams

→ Challenge: high-intensity electron beams

Emission of polarized electrons from GaAs:

$$E_\gamma < 1.76 \text{ eV} \quad \text{or} \quad \lambda > 705 \text{ nm}$$

Photoemission threshold for GaAs:

$$E_{\text{th}} > 5.52 \text{ eV} \quad \text{or} \quad \lambda < 225 \text{ nm}$$

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Activation with NEA layer required to reduce work function!

Emission of polarized electrons from GaAs:

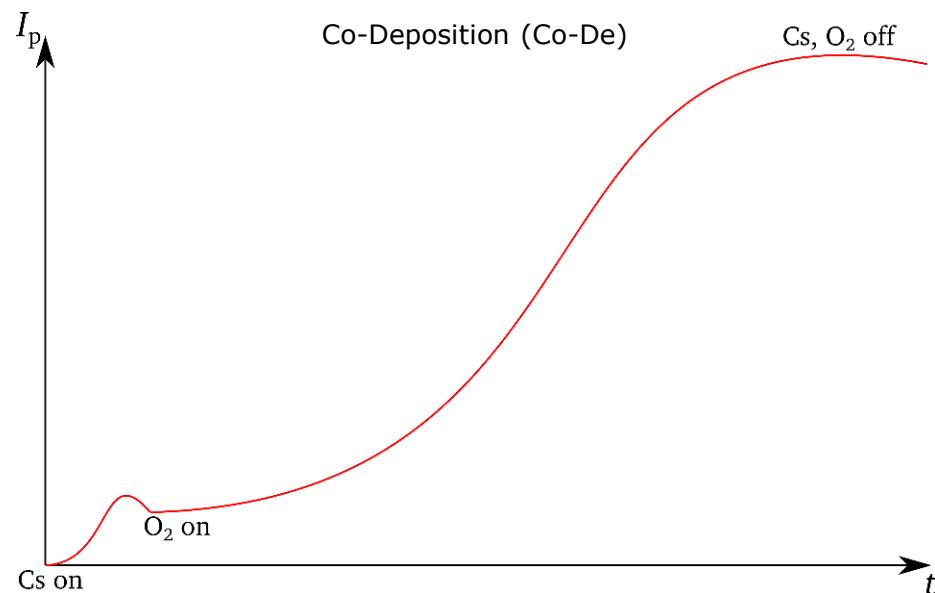
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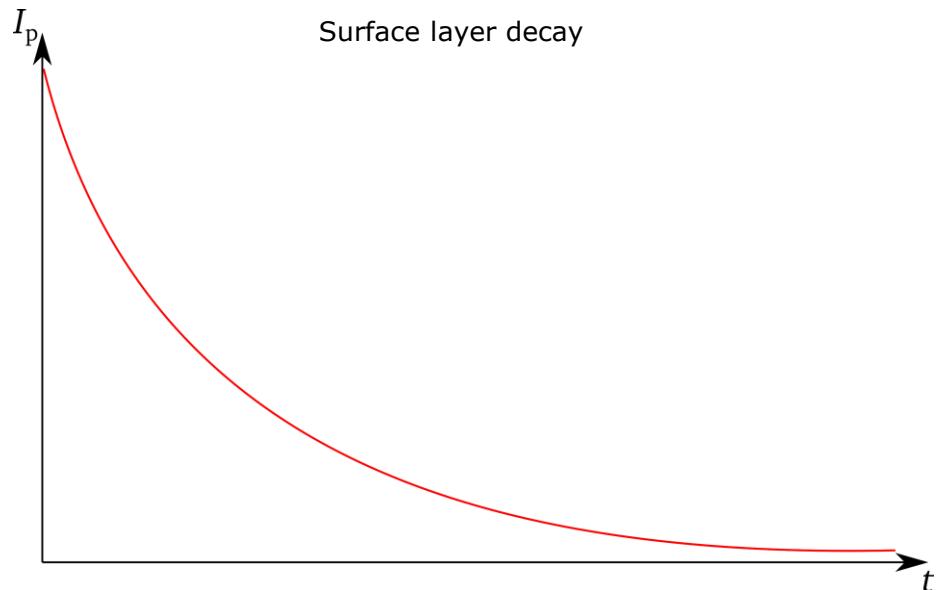
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Activation with NEA layer required to reduce work function!



Main parameters:  $\eta_0$ ,  $\tau$ ,  $Q(\tau)$

$$\eta(\lambda) = \left| \frac{hc_0 I_p}{e P_L \lambda} \right| \cdot 100\%$$

$$\eta(t) = \eta_0 \cdot e^{-t/\tau}$$

$$Q(\tau) = I_0 \cdot \tau \cdot \left(1 - \frac{1}{e}\right) \approx 0.63 \cdot I_0 \cdot \tau$$

Emission of polarized electrons from GaAs:

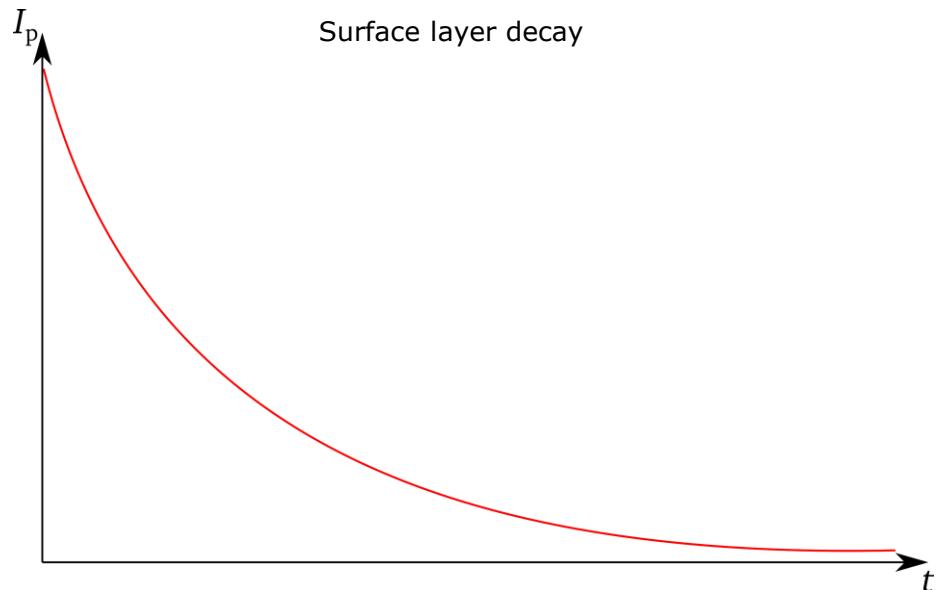
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Activation with NEA layer required to reduce work function!



Outcome depends  
on operator input



Dedicated  
activation  
studies

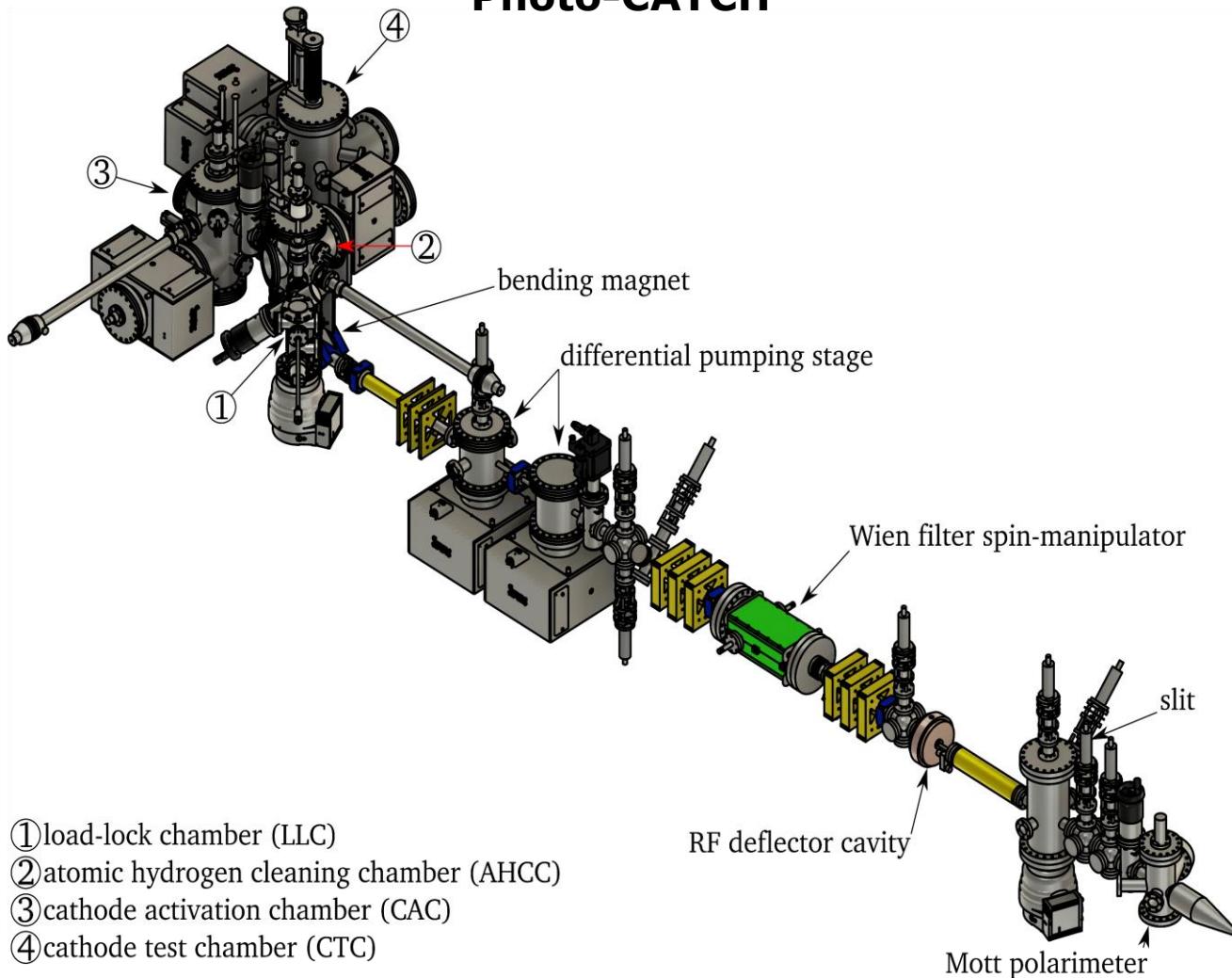
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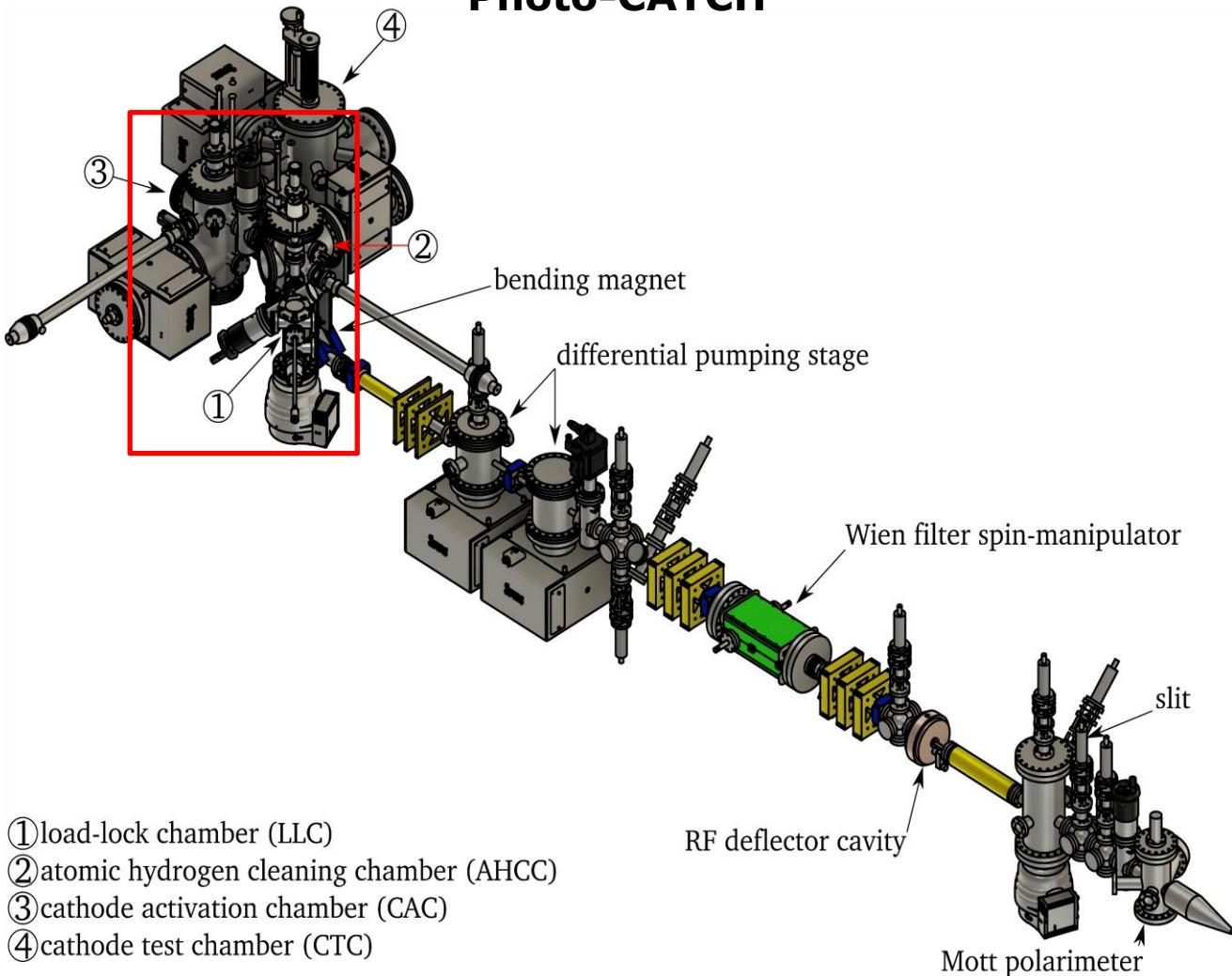
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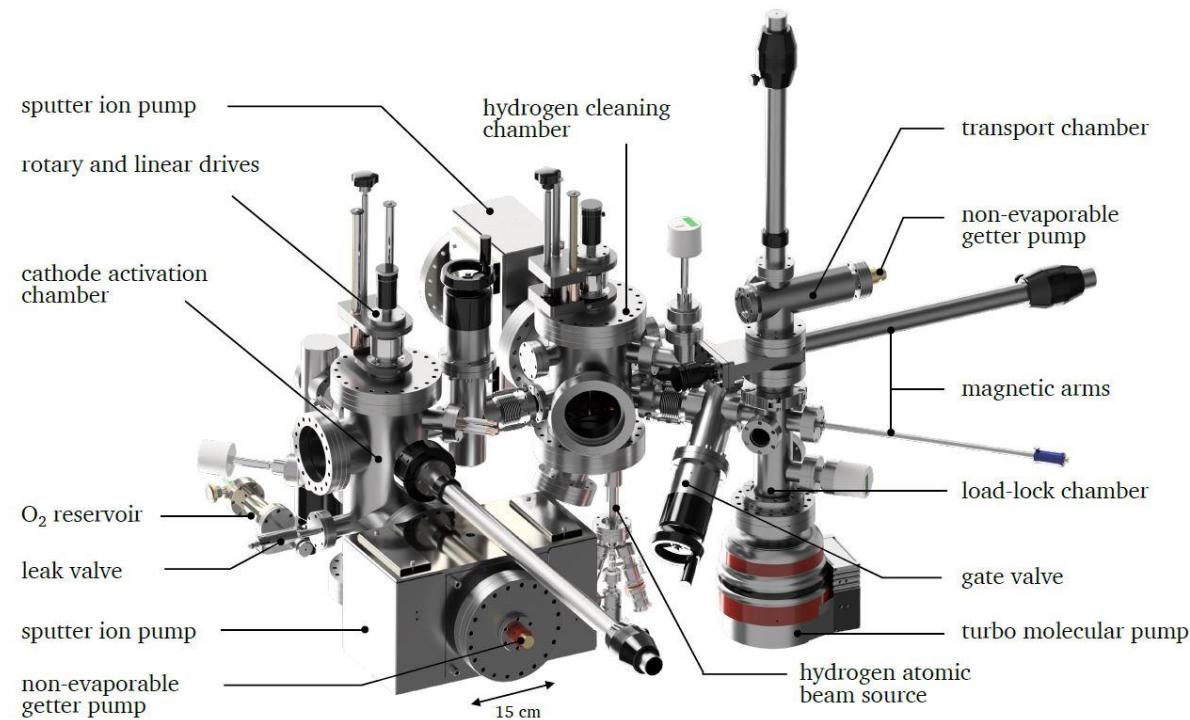
## Photo-CATCH



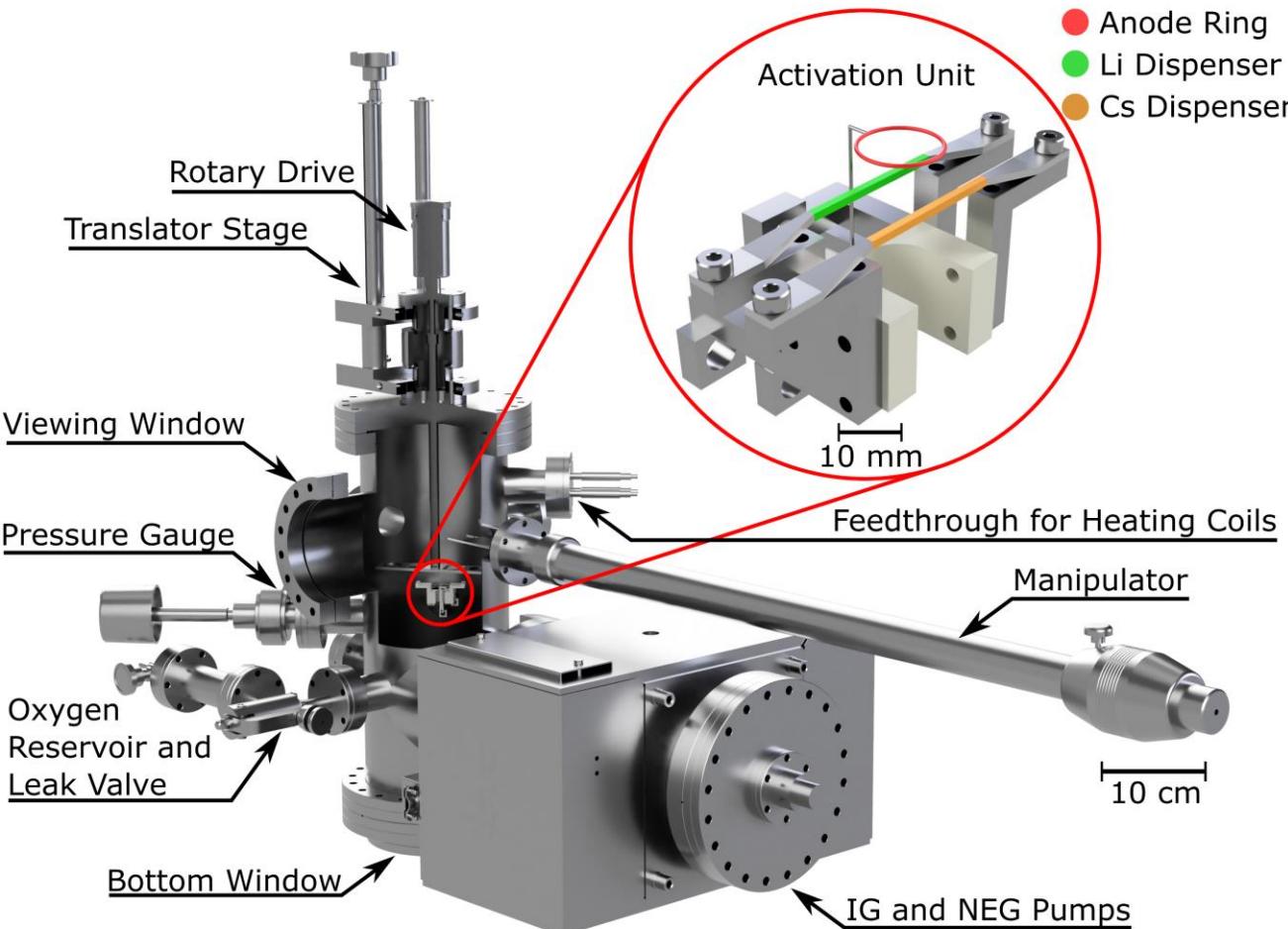
## Photo-CATCH



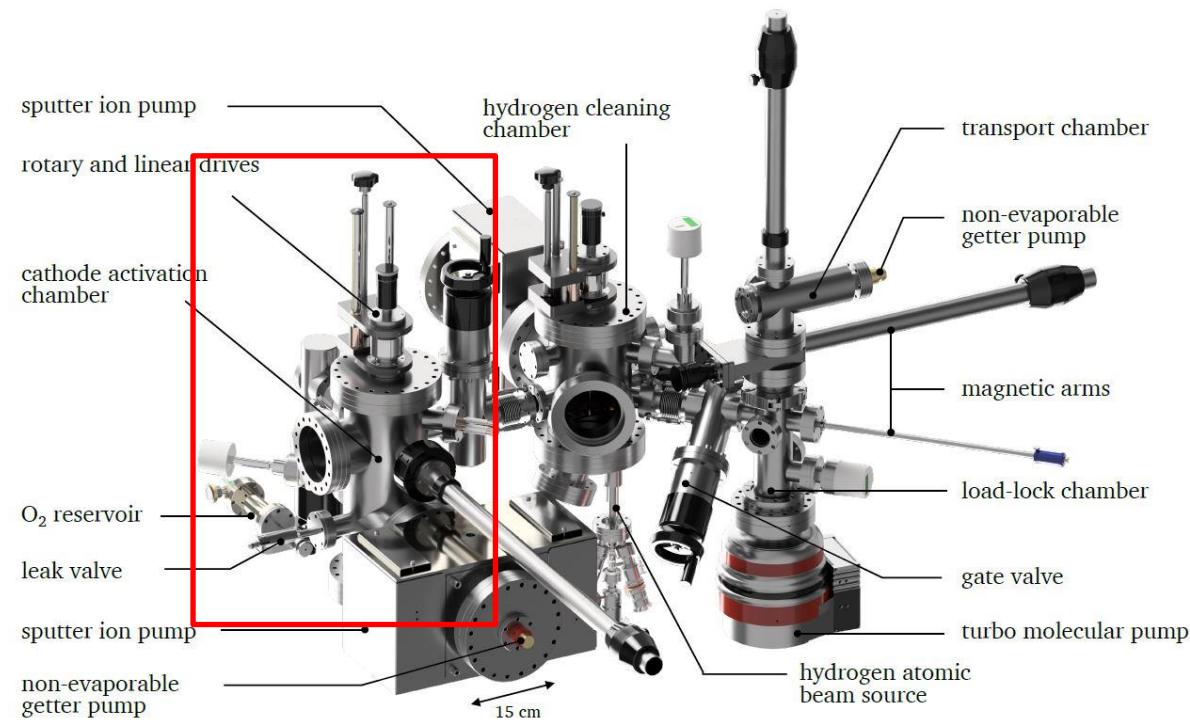
## Activation & Cleaning System



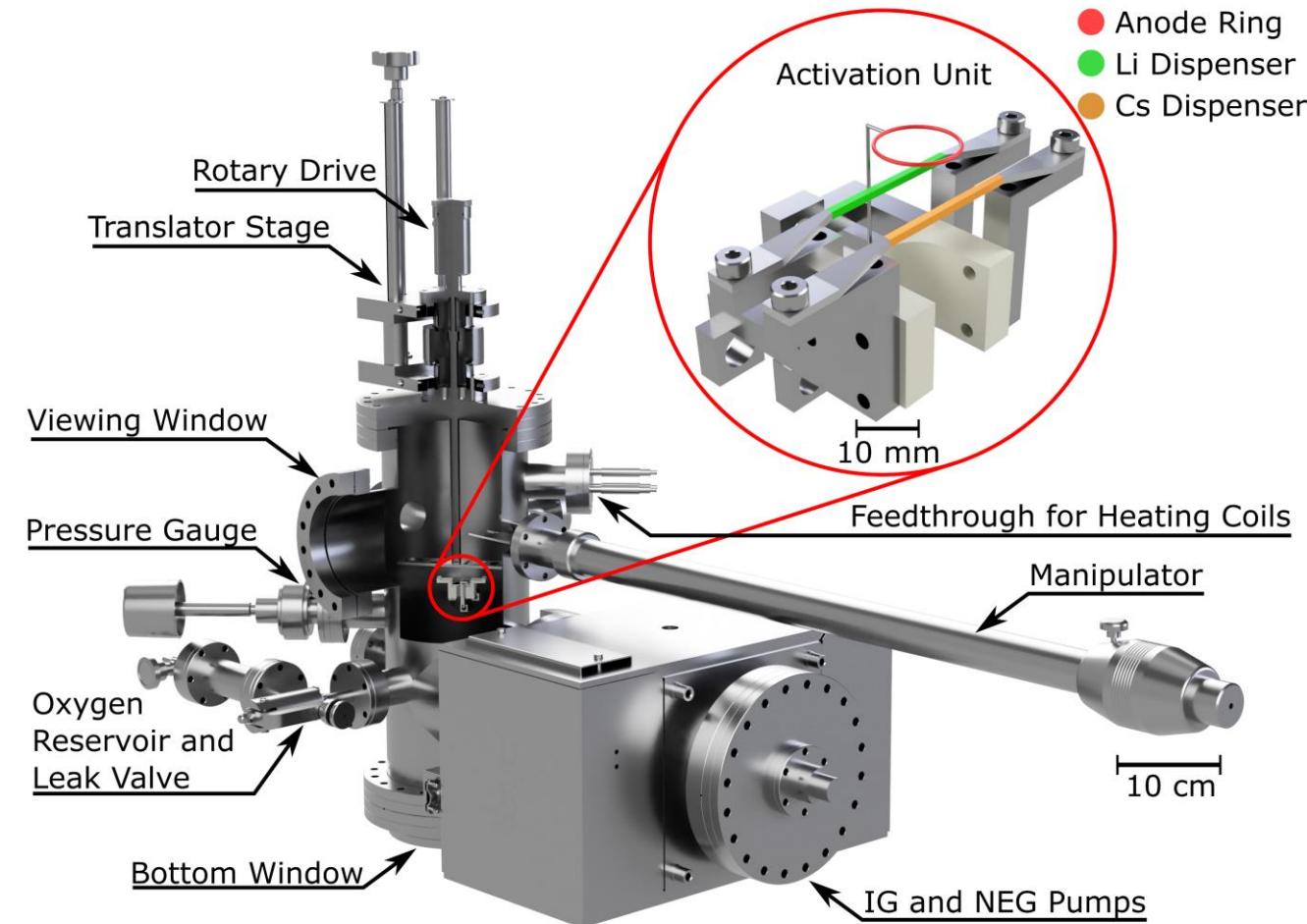
## Activation Chamber



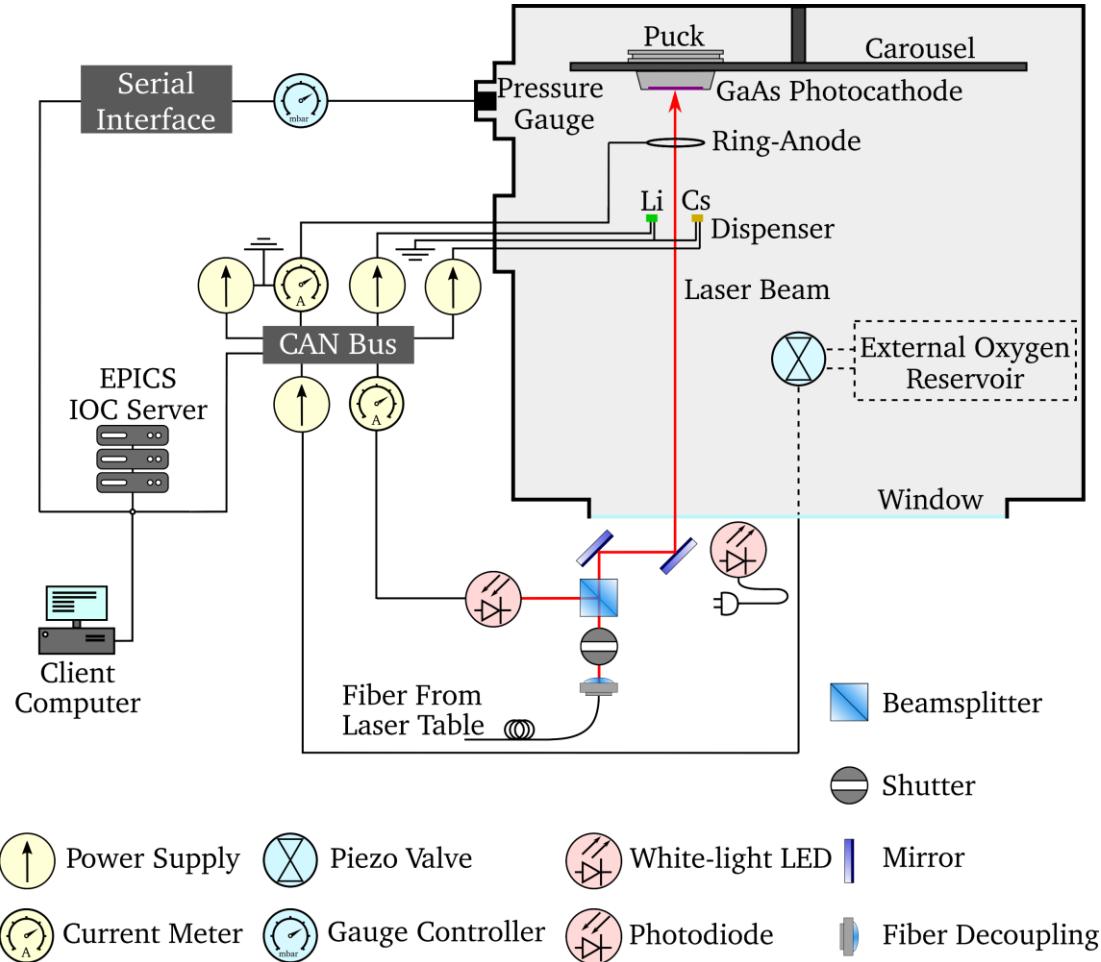
## Activation & Cleaning System



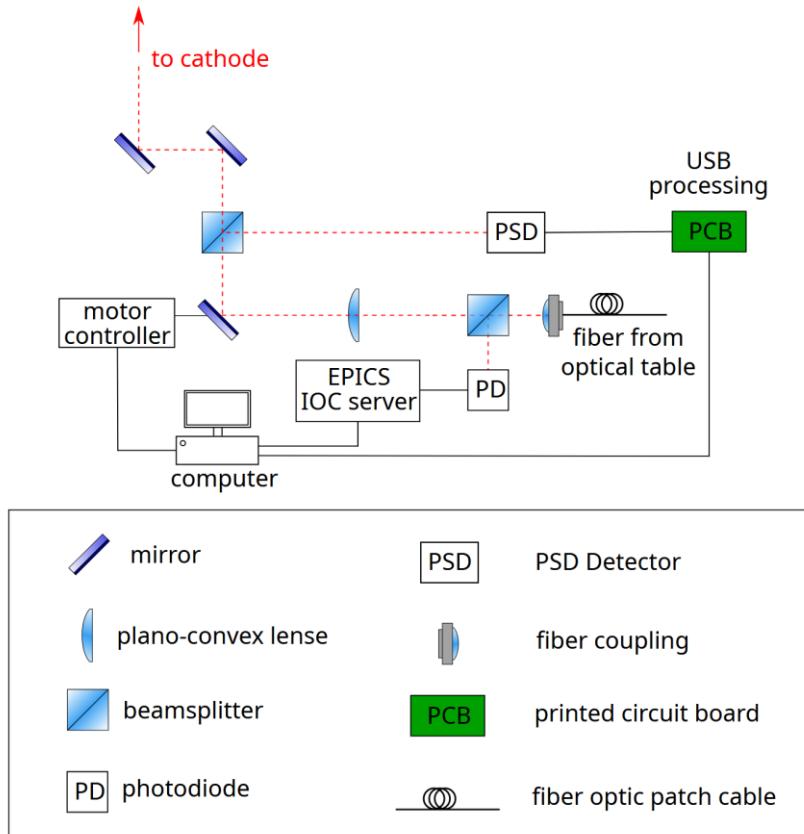
## Activation Chamber



## Activation Setup

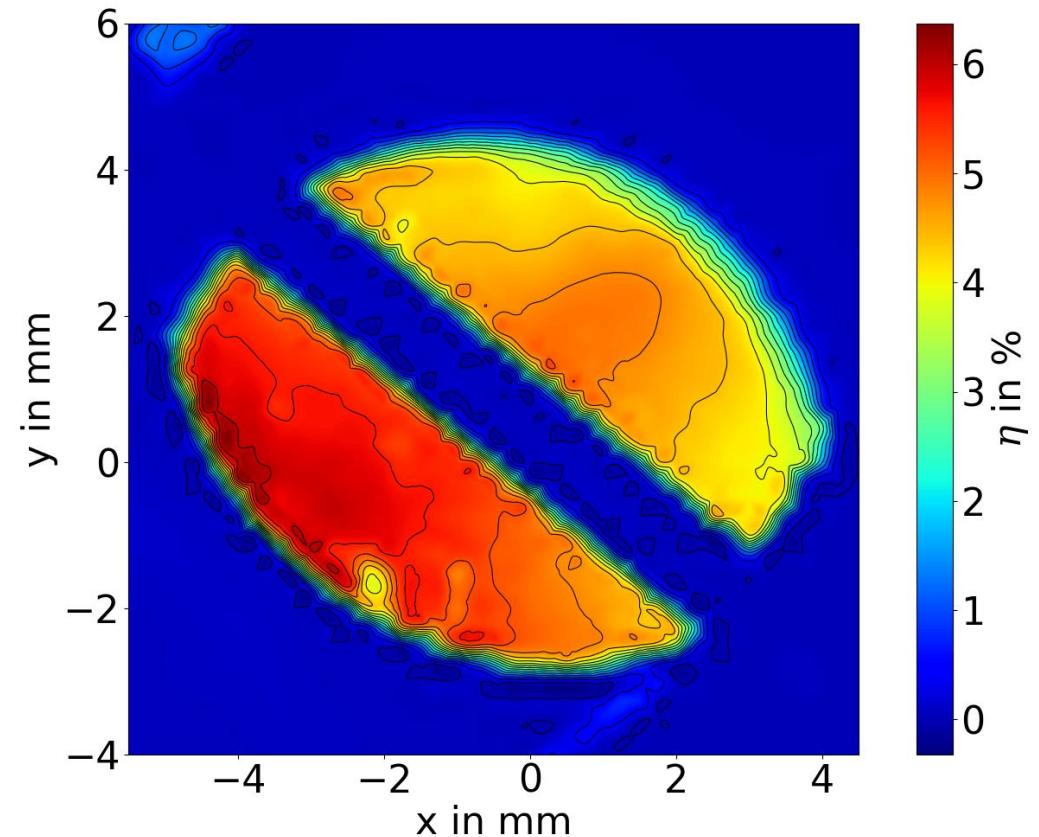
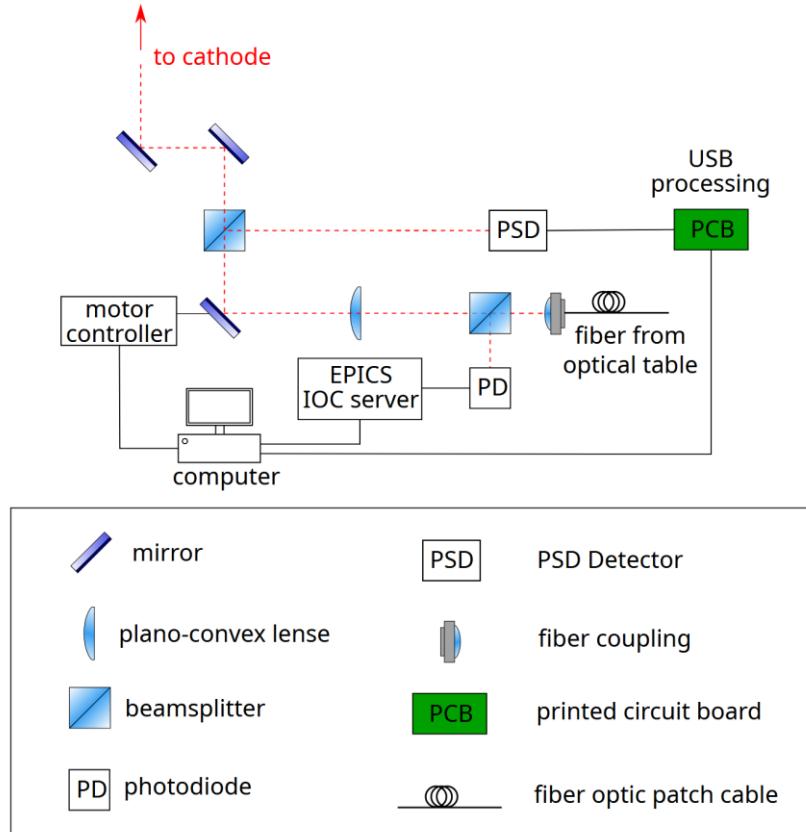


## QE scan setup



- Measure QE distribution on photocathode surface
- Dedicated laser beamline below activation chamber
- Move laser-spot using piezo-electric mirror mount
- Feedback position control via position-sensitive diode
- Python-based

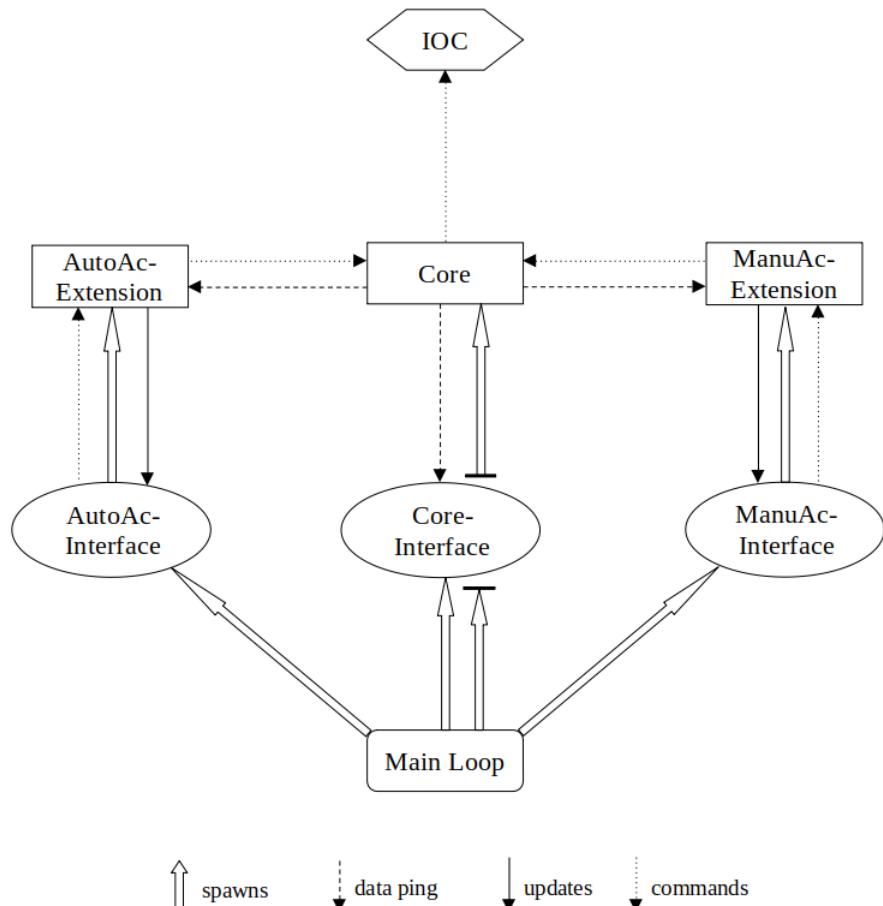
## QE scan setup



Implementation successful!

## Adaptive Automated Activation using PyCAT

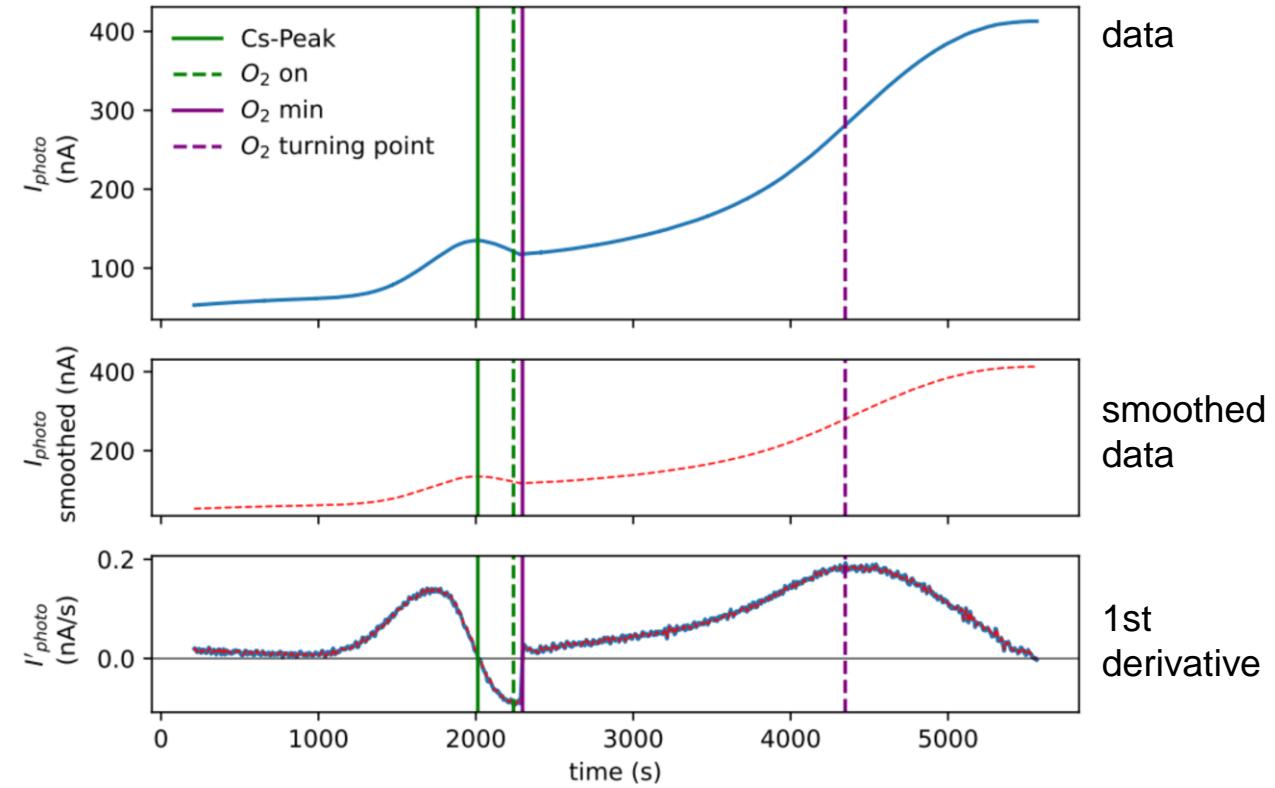
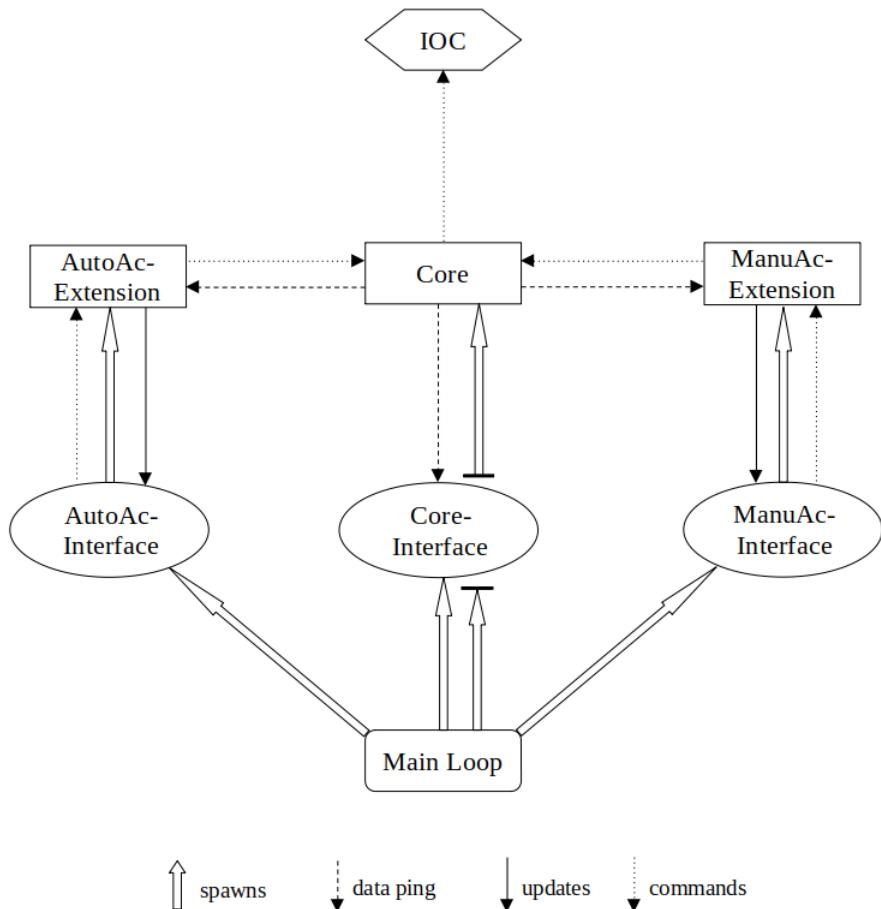
### Python Cathode Activation Terminal



- Advanced development following successful preliminary, timer-based tests
- Based on automatic curve analysis (python code)
- Parameters derived in real time during activation process

## Adaptive Automated Activation

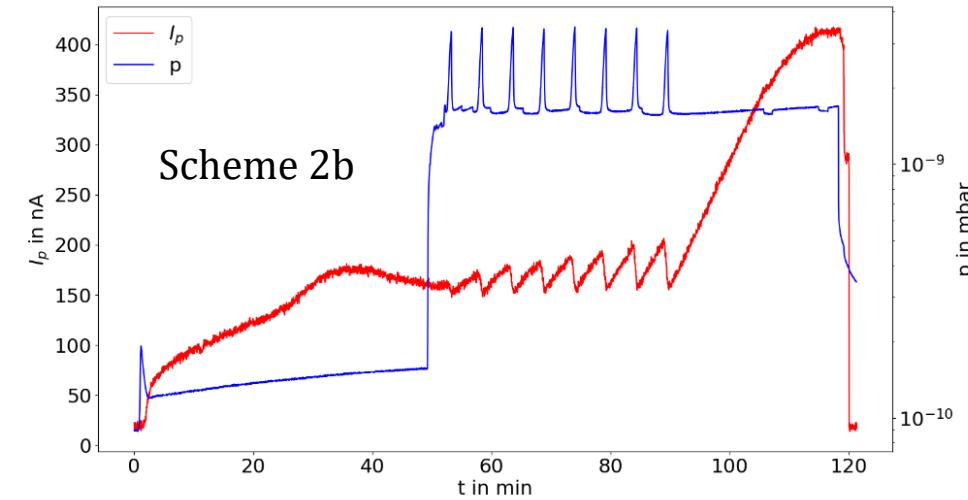
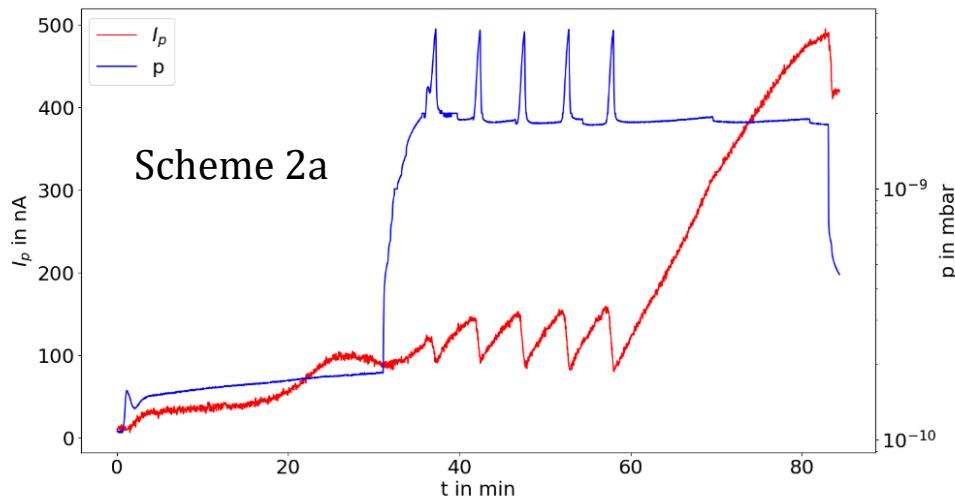
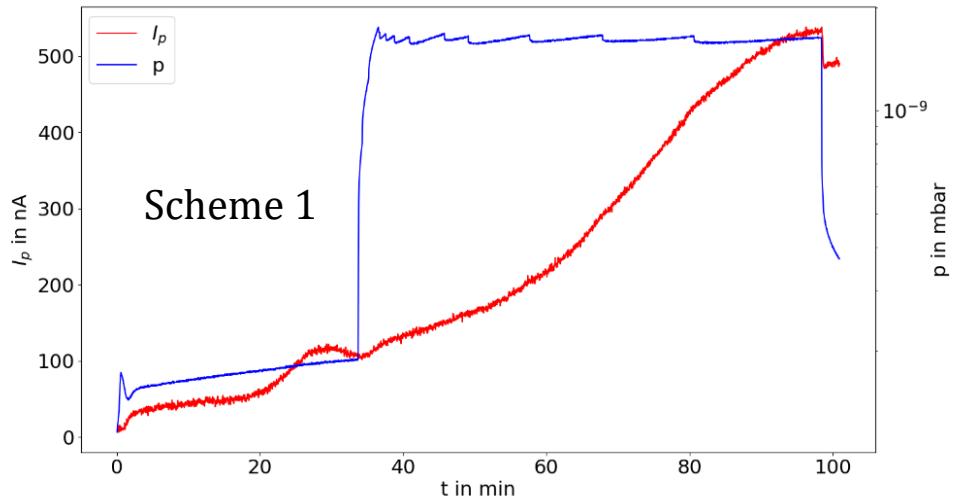
### Python Cathode Activation Terminal



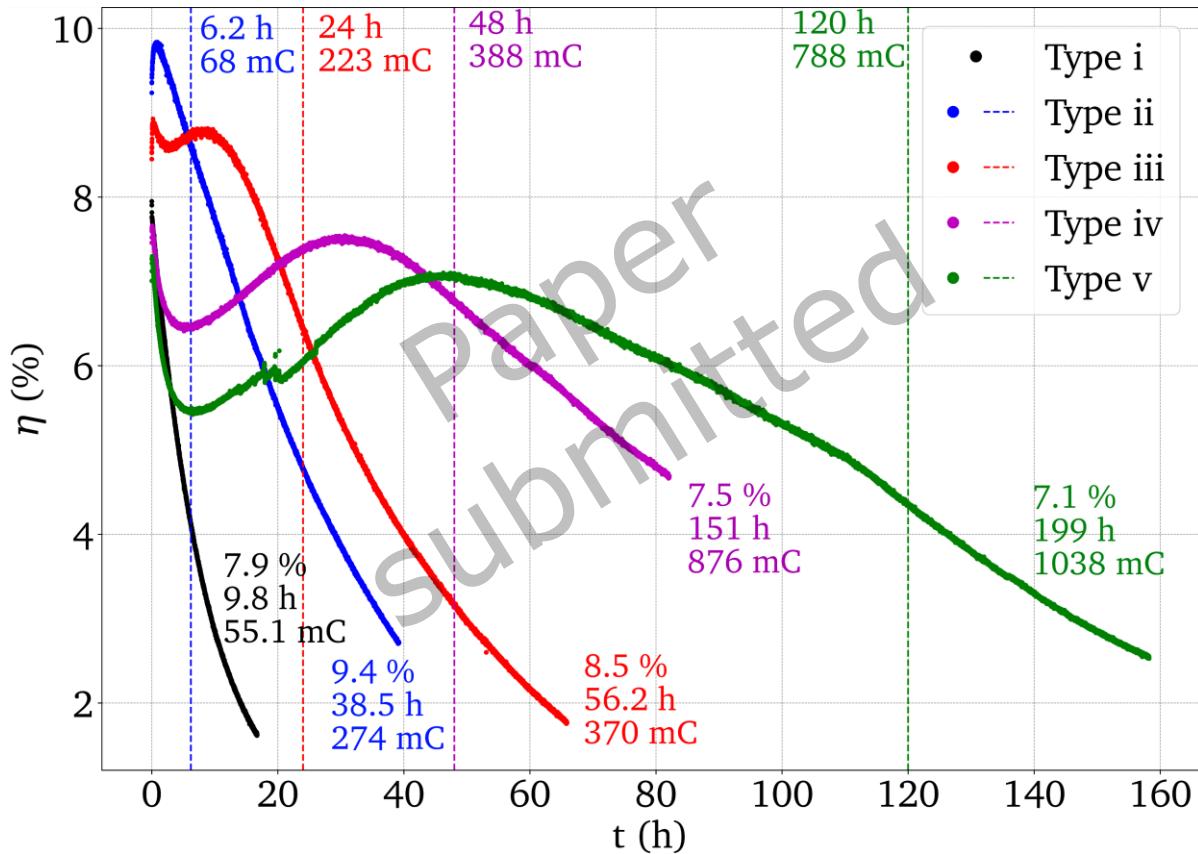
first tests successful!

## Li-enhanced activation

- Goal: enhanced lifetime
- Co-De with pulsed Li, based on previous study
- Scheme 1: Cs + O<sub>2</sub>
- Scheme 2a: Cs + O<sub>2</sub> + Li, 5 pulses
- Scheme 2b: Cs + O<sub>2</sub> + Li, 8 pulses

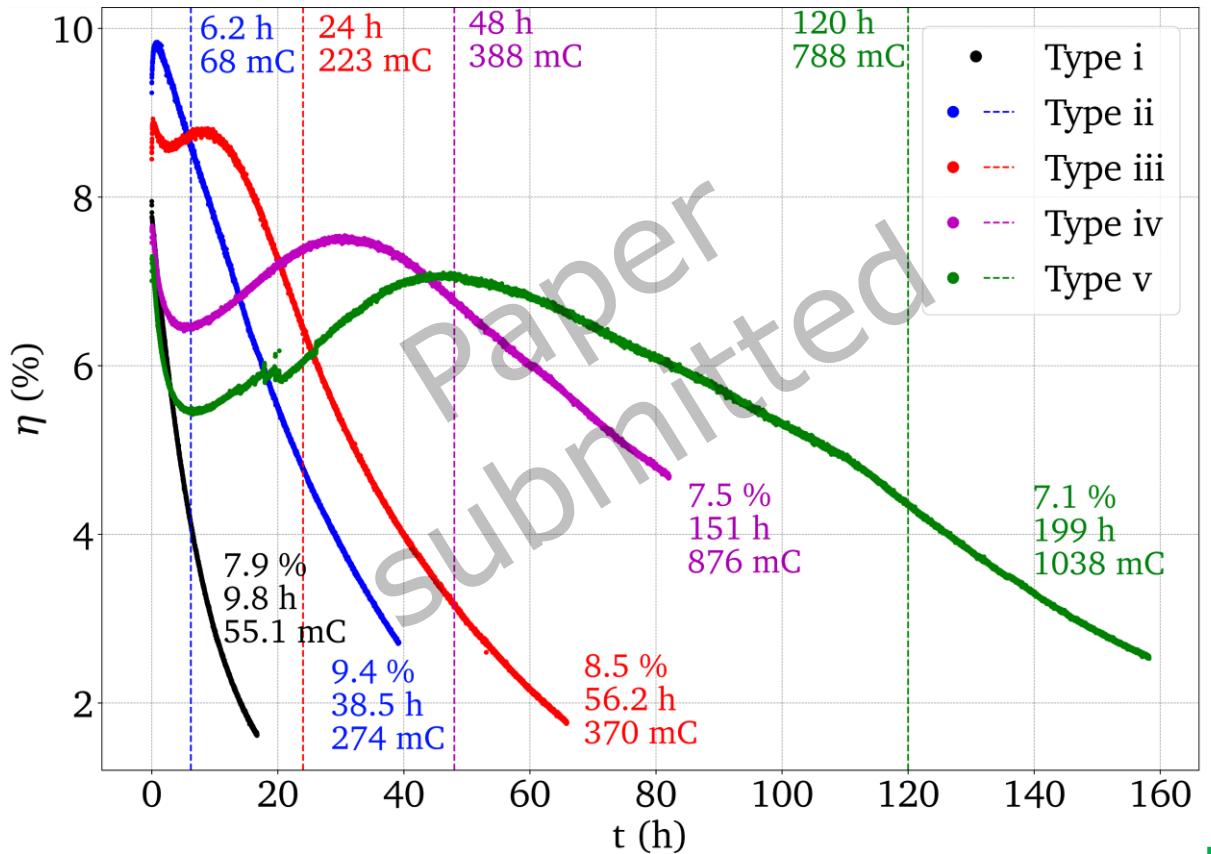


## Li-enhanced activation



- QE & Lifetime measurements in activation chamber
- $P_{\text{laser}} = (50 \pm 5) \mu\text{W}$ ,  $\lambda = (785 \pm 2) \text{ nm}$ ,  $U_{\text{bias}} = 100 \text{ V}$
- 5 types of activations:
  - Scheme 1, no prior scheme 2
  - Scheme 1, subsequent to scheme 2a
  - Scheme 2a, subsequent to scheme 1
  - Scheme 2b, subsequent to scheme 1
  - Scheme 2b, subsequent to scheme 2b
- Effect of Li on subsequent activations observed

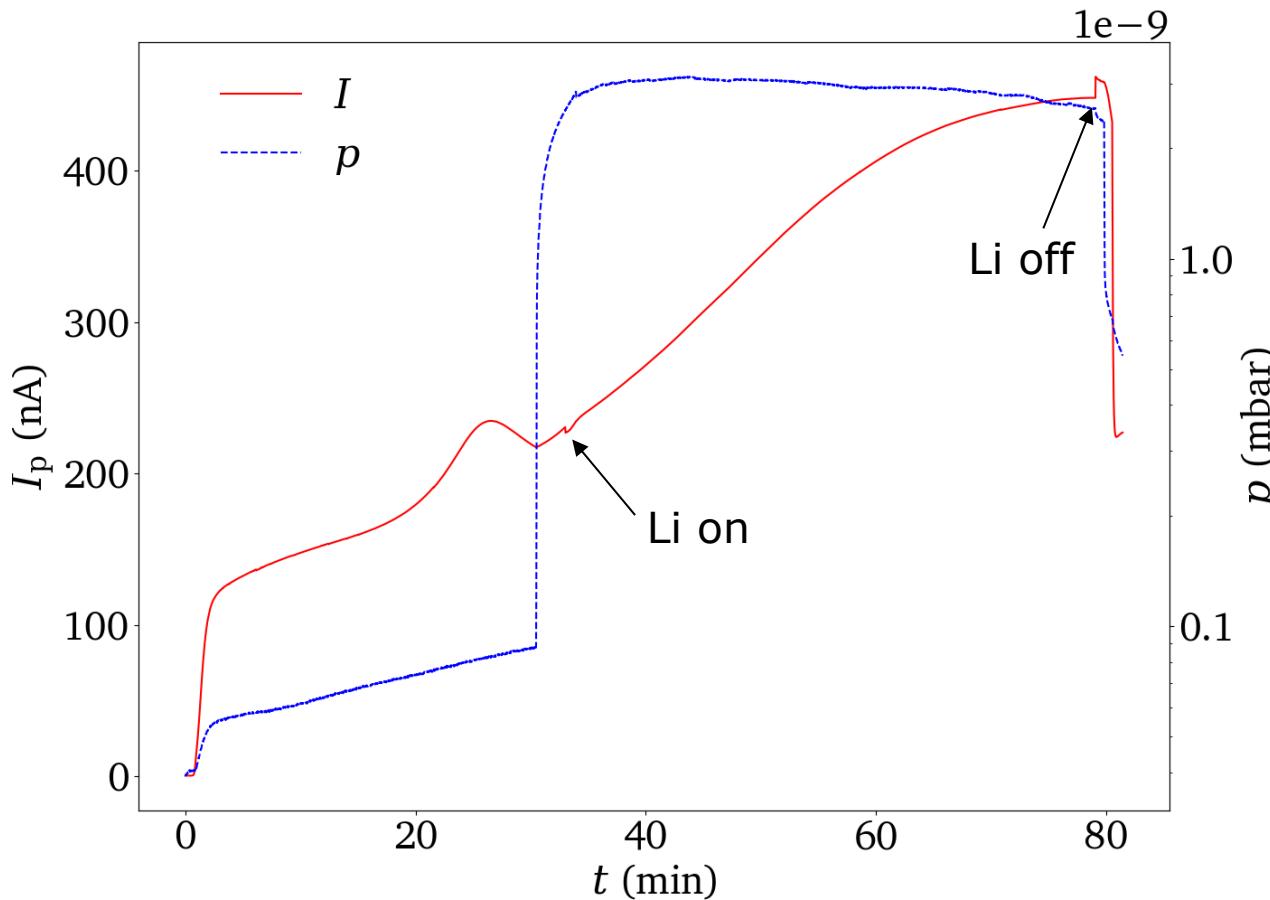
## Li-enhanced activation



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- 5 types of activations:
  - Scheme 1, no prior scheme 2
  - Scheme 1, subsequent to scheme 2a
  - Scheme 2a, subsequent to scheme 1
  - Scheme 2b, subsequent to scheme 1
  - Scheme 2b, subsequent to scheme 2b
- Effect of Li on subsequent activations observed

Significant increase in  $\tau$  (up to factor 19) and  $Q(\tau)$  (up to factor 16.5) observed!

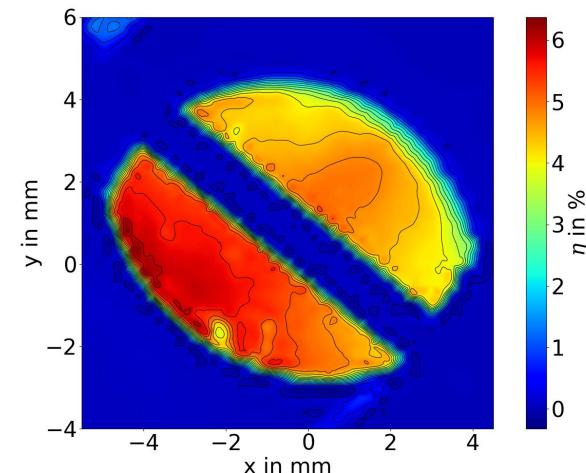
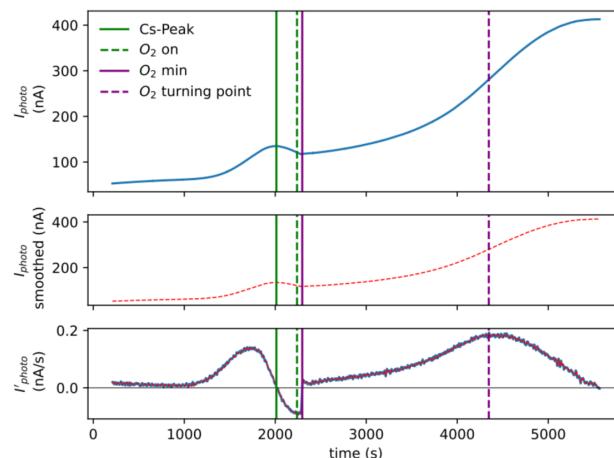
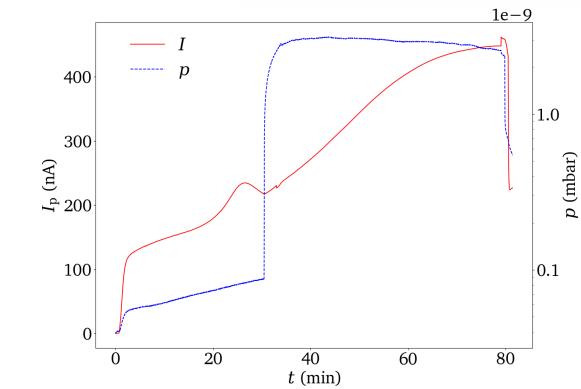
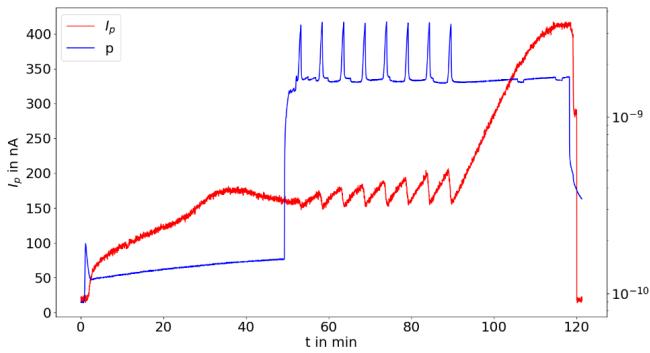
## Li-enhanced activation (cont.)



- Idea: simultaneous co-deposition of Li along with Cs and O<sub>2</sub> instead of pulsed Li
- First activation tests successful, QE comparable to Cs+O<sub>2</sub> activation
- BUT: first lifetime tests show no improvement
- Additional tests with higher Li dosage as well as comparison with pulsed scheme ongoing

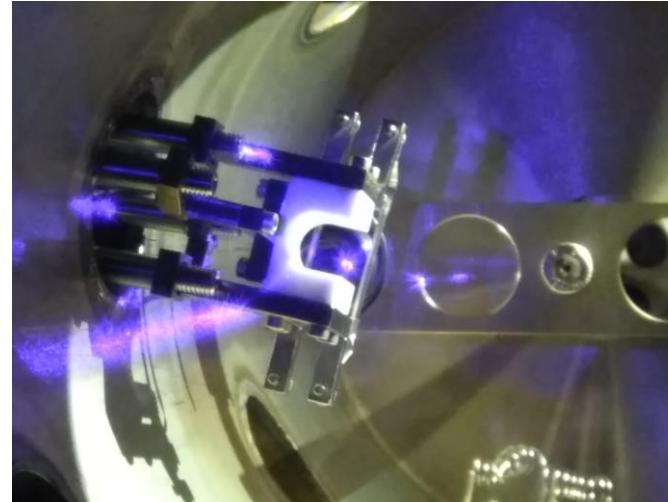
- ✓ Implementation of QE-scan setup
- ✓ Development of automated activation scheme
- ✓ Implementation of Li-enhanced activation yielding significant increase in lifetime
- ⌚ Benchmark automated vs manual activation
- ⌚ Test of Li Co-Deposition
- ⌚ Additional lifetime measurements of Li-enhanced activation

## Conclusion



## Outlook

- Additional studies with Li-enhanced activation
- Further sophistication of automated activation scheme
- Experiments with Photo-CATCH gun
- High-polarization cathodes
- Cryogenic gun development





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# THANK YOU!

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